

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V _{DSS}	-40	V		
Gate-Source Voltage			V_{GSS}	±25	V
Continuous Durin Courset (Note 5) V - 40V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-8.5 -6.8	А
Continuous Drain Current (Note 5) V _{GS} = -10V	t<10s	T _A = +25°C T _A = +70°C	I _D	-13 -10.5	А
Continuous Durin Courset (Nata C) / 40//	Steady State	T _A = +25°C T _A = +70°C	I _D	-11 -8.7	А
Continuous Drain Current (Note 6) V _{GS} = -10V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-17 -13.5	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	-100	Α
Maximum Body Diode Continuous Current (Note 6)			Is	-3.5	Α
Avalanche Current (Note 7)			I _{AS}	-22	Α
Avalanche Energy (Note 7)			E _{AS}	242	mJ

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Payer Dissipation (Note 5)	T _A = +25°C	Б	1.3	W
Total Power Dissipation (Note 5)	T _A = +70°C	P_{D}	0.8	
Thermal Decistors of Lunction to Architect (Note 5)	Steady state	П	96.4	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	40.6	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	Б	2.1	W
Total Power Dissipation (Note 6)	T _A = +70°C	P_{D}	1.4	
Thermal Desistance, Junction to Ambient (Note 6)	Steady state	П	55	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	24	°C/W
Thermal Resistance, Junction to Case (Note 6)		$R_{ heta JC}$	4.15	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

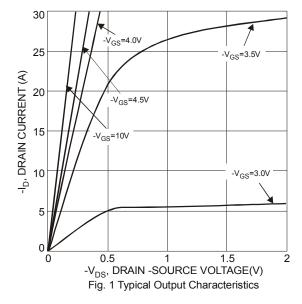
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

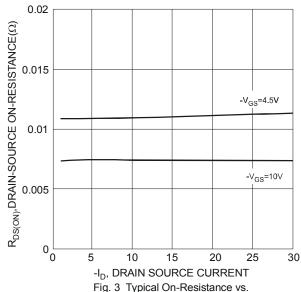
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}		_	-1	μA	$V_{DS} = -40V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	$V_{GS(th)}$	-1.5	-2	-2.5	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
Static Drain-Source On-Resistance	В		7	11	mΩ	$V_{GS} = -10V, I_D = -9.8A$
Static Drain-Source On-Resistance	R _{DS (ON)}		9	15		$V_{GS} = -4.5V, I_D = -9.8A$
Forward Transfer Admittance	Y _{fs}	_	26	_	S	$V_{DS} = -20V, I_{D} = -9.8A$
Diode Forward Voltage	V_{SD}	_	-0.7	-1	V	$V_{GS} = 0V, I_{S} = -1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}		4234	_		V _{DS} = -20V, V _{GS} = 0V f = 1MHz
Output Capacitance	Coss	_	1036	_	pF	
Reverse Transfer Capacitance	C _{rss}		526	_		
Gate Resistance	R _G		7.77	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge	Q_g	_	47.5	_	V 00V V 5V	
Gate-Source Charge	Q_{gs}		14.2	_	nC	$V_{DS} = -20V, V_{GS} = -5V$ $I_{D} = -9.8A$
Gate-Drain Charge	Q_{gd}	_	13.5	_		
Turn-On Delay Time	t _{D(on)}	_	13.2	_		V_{GS} = -10V, V_{DD} = -20V, R_{G} = 6 Ω , I_{D} = -1A, R_{L} = 20 Ω
Turn-On Rise Time	t _r	_	10	_	200	
Turn-Off Delay Time	t _{D(off)}	_	302.7	_	ns	
Turn-Off Fall Time	t _f	_	137.9	_		

Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate
- 7. UIS in production with L = 0.1mH, TJ = +25°C
- 8 .Short duration pulse test used to minimize self-heating effect.
- 9. Guaranteed by design. Not subject to production testing.







Drain Current and Gate Voltage

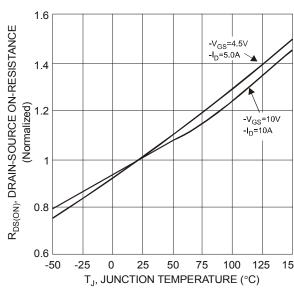
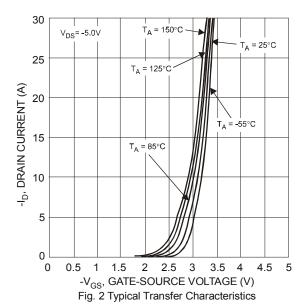
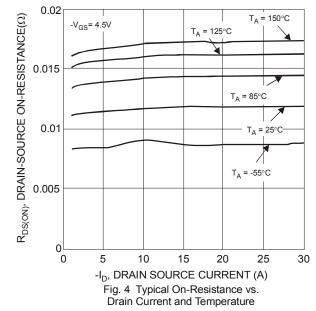


Fig. 5 On-Resistance Variation with Temperature





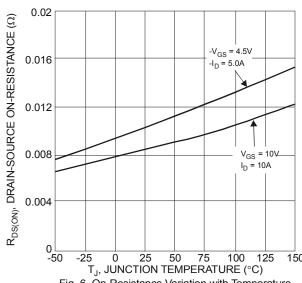


Fig. 6 On-Resistance Variation with Temperature



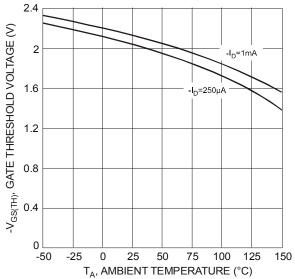
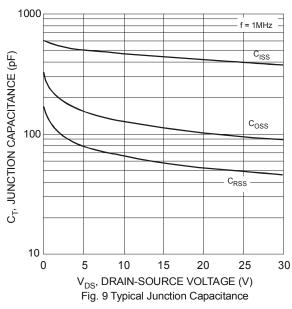
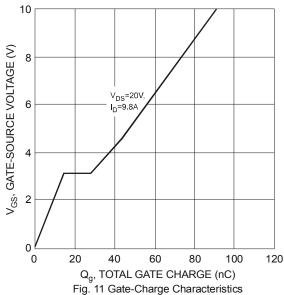
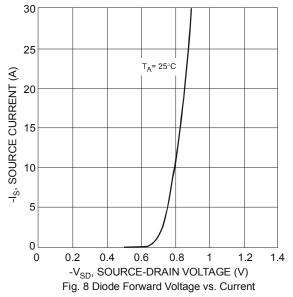


Fig. 7 Gate Threshold Variation vs. Ambient Temperature







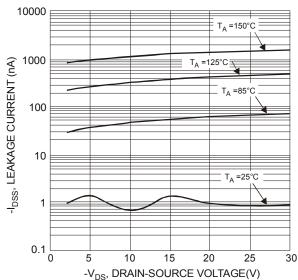


Fig. 10 Typical Drain-Source Leakage Current vs. Voltage

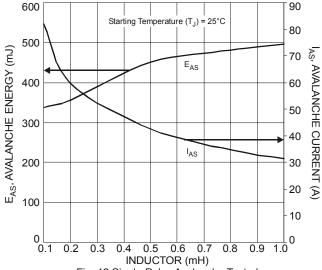
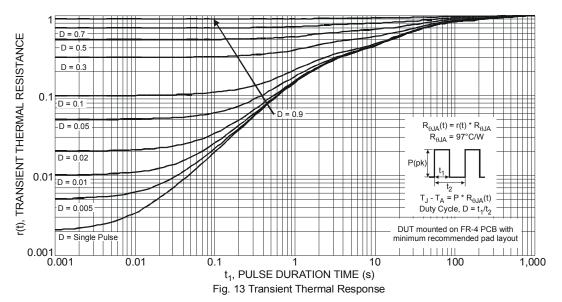


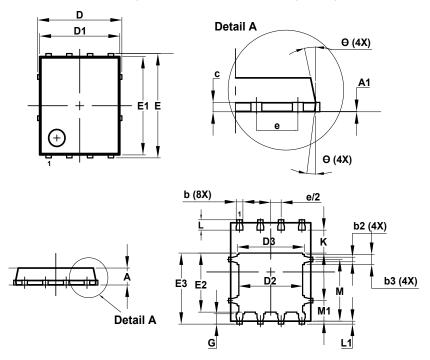
Fig. 12 Single-Pulse Avalanche Tested





Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

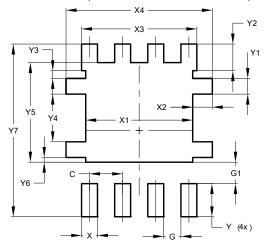


POWERDI5060-8						
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05	_			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D	5.15 BSC					
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90 4.30		4.10			
Е	6.15 BSC					
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	_	_			
L	0.51	0.71	0.61			
L1	0.050	0.20	0.175			
M	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
Θ1	6°	8°	7°			
All Dimensions in mm						



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

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